

Graphical Abstract

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Highlights

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Non-equilibrium free-energy calculation of phase-boundaries using LAMMPS

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Abstract

We present a guide to compute the phase-boundaries of classical systems using a dynamic Clausius-Clapeyron integration (dCCI) method within the LAMMPS (Large-scale Atomic/Molecular Massively Parallel Simulator) code. The advantage of the dCCI method gives coexistence curves spanning a wide range of thermodynamic states from relatively short a single non-equilibrium simulations. We describe the state of art of the non-equilibrium free-energy methods as allow us compute the Gibbs free-energy in wide interval of pressure and/or temperature and the dCCI method in details, discuss their implementation in the LAMMPS package and make available source code, scripts as well as auxiliary files. As an illustrate example we determine the phase diagram of silicon in a range of pressures covering from 0 to 15 GPa and temperatures above the melting points, to obtain the phase boundaries and triple points between the diamond, liquid and β -Sn phases are reported.

Keywords: Non-equilibrium free-energy calculations, Dynamics
Clausius-Clapeyron integration method, Molecular dynamics, LAMMPS

1. Introduction

The knowledge of phase diagrams is the great importance for many research areas in physics, chemistry, and engineering. The phase diagram is

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map used to show which conditions of pressure, temperature, volume, etc, can be found specify phase of the systems and the phases boundaries.

The determination of phase diagrams by computer simulation requires the computation of the free energy of the various phases of the system, this task is far from trivial. The difficulties stem from the fact that entropy and free energies depend on the volume in phase space available to the system, in contrast to other thermodynamic properties, such as internal energy, enthalpy, temperature, pressure, etc., that can be easily computed as simple averages of functions of the phase space coordinates.

The determination of phase diagrams by computer simulation can be achieved by the employ free energy evaluation techniques like thermodynamic integration (TI)[1] which consists on the construction of a sequence of equilibrium states along a path between two thermodynamic states of interest, the calculated free-energy difference between these two states is essentially exact, since the free energy of the reference system is known, the absolute free energy of the system of interest is readily obtained. In practice, since the integration along the thermodynamic path is performed numerically, it requires the calculation of several ensemble averages, which is computationally very demanding.

In recent years, several studies[2, 3, 4, 5, 6] has been proving the efficiency of the non-equilibrium (NE) techniques, make free energy calculations much more accessible[2, 4], inclusive available in the widely used LAMMPS molecular dynamics (MD) package[7]. Contrary to equilibrium TI method, the NE approaches estimate the desired free-energy difference by traversing the thermodynamic path between the system of interest and the reference in an explicitly time-dependent process and have shown to give accurate results using only a few relatively short non-equilibrium simulations.

However, several NE calculations are required for each coexistence condition between the phases of the system, necessary to map correctly the phase boundaries. In order to optimize the calculation of phase boundaries, it was proposed by de Koning et al.[8] a dynamical integration of the Clausius-Clapeyron (dCCI) equation using non-equilibrium simulations. This method allows the calculation of the phase boundary using, in principle with a single simulation, whose length is comparable to a regular equilibrium simulation.

In this paper we demonstrate the potential of dCCI method by using them to obtain, entirely from atomistic simulations, the phase diagram in a wide range of temperatures and pressures, focusing on the implementation in the widely used LAMMPS MD package. We show how the NE methods

can be used to compute the Gibbs free-energy in wide interval of temperature and/or pressure and with the dCCI method can be used to accurately and efficiently compute the phase boundaries for atomistic systems. We provide excerpts from the used LAMMPS scripts to exemplify the practical details of the calculations. Complete LAMMPS scripts, source codes and post-processing tools are also made available. As illustration we perform non-equilibrium free-energy calculation of phase-boundaries for silicon, described by the Stillinger-Weber[9] potential.

The paper is organized as follows. In Sec. 2 we review the relevant aspects of non-equilibrium free-energy methods to calculate the Gibbs free-energy along isothermal and isobaric paths. Sec. 3 provides the details of the dCCI methodology, in which from a given initial coexistence condition one is able to determine the entire phase boundary from a single non-equilibrium simulation. Sec. 4 we describe the application of dCCI to compute the phase diagram of Si. We end with a summary and conclusions in Sec. 5.

2. Non-equilibrium free-energy methods

The TI method[1] has been widely used to compute Helmholtz free energies difference by using the calculation of reversible work. It consists of the construction of a path connecting two thermodynamic states by defining a parametrized Hamiltonian $H(\lambda)$, where λ is a coupling parameter describing the interpolation between the two ends of the thermodynamic path.

It is straightforward to show, starting from the definition of the partition function, that the Helmholtz free-energy difference between the two equilibrium states corresponding to $H(\lambda_i)$ and $H(\lambda_f)$ is given by the reversible work W_{rev} done along quasistatic process to connect these states, i.e.

$$\Delta F = F(\lambda_f) - F(\lambda_i) = \int_{\lambda_i}^{\lambda_f} \left\langle \frac{\partial H}{\partial \lambda} \right\rangle d\lambda \equiv W_{rev}, \quad (1)$$

where $\langle \dots \rangle_\lambda$ is the canonical ensemble average at a particular value of parameter and $\frac{\partial H}{\partial \lambda}$ is the so-called driving-force. In this approach, the integral is discretized on a grid of λ -values for each value between λ_i and λ_f a separated equilibrium simulation is executed, to obtain accurate results.

In the NE approach, the adiabatic switching[10] (AS) method estimates the integral of Eq. 1 instead of an integration over equilibrium ensemble averages, is replaced by an integration over instantaneous values in terms of

the dynamical work done along a single simulation in which $\lambda = \lambda(t)$ changes continuously throughout the simulation

$$W_{dyn} = \int_0^{t_s} \frac{d\lambda}{dt} \frac{\partial H(\lambda)}{\partial \lambda} \Big|_{\lambda(t)} dt, \quad (2)$$

where t_s is the total time of the switching process and W_{dyn} is the dynamical work done. Due to the irreversible nature of the process, dissipative entropy is produced, causing W_{dyn} to be a stochastic variable whose mean value, by the second law of thermodynamics, differs from W_{rev} by the relation

$$\Delta F = W_{rev} = \overline{W}_{dyn} - \overline{Q}_{diss}, \quad (3)$$

where the overbar means an average over an ensemble of realizations of the AS process and $\overline{Q}_{diss} \geq 0$ is the average dissipated heat, which is zero only in the quasistatic limit ($t_s \rightarrow \infty$). However, provided that the non-equilibrium process is sufficiently “close” to the ideally quasistatic process for linear response theory to be valid, it can be shown that the systematic error can be eliminated by combining the results of the processes realized in both directions (forward and backward). Accordingly, one has

$$\Delta F = \frac{1}{2} [\overline{W}_{dyn}^{i \rightarrow f} - \overline{W}_{dyn}^{f \rightarrow i}], \quad (4)$$

where we have used the fact that for a linear-response non-equilibrium process the heat dissipated in both process are identically $\overline{Q}_{diss}^{i \rightarrow f} = \overline{Q}_{diss}^{f \rightarrow i}$. Similarly, the heat dissipated can be estimated by

$$\overline{Q}_{diss}^{i \rightarrow f} = \overline{Q}_{diss}^{f \rightarrow i} = \frac{1}{2} [\overline{W}_{dyn}^{i \rightarrow f} + \overline{W}_{dyn}^{f \rightarrow i}], \quad (5)$$

the Eqs. 4 and 5 can be used to the monitoring of the convergence of ΔF and the heat dissipation as a function of switching time t_s . The AS method can lead to significant efficiency gains when compared to standard equilibrium methods, provides accurate estimates of ΔF using only a few relatively short non-equilibrium simulations.

Next we discuss the application of three specific thermodynamic paths for $H(\lambda)$ that allow the calculation of, (i) the Helmholtz free-energy difference between two systems described by different Hamiltonians, (ii) the temperature-dependence of the Gibbs free-energy for a given system Hamiltonian along isobaric path, and (iii) the pressure-dependence of the Gibbs free-energy for a given system Hamiltonian along isotherm path.

2.1. *Helmholtz Free-energy difference between two systems: Hamiltonian interpolation method*

Suppose we wish to compute the Helmholtz free-energy of some system of interest described by a Hamiltonian H_{int} of the form

$$H_{int} = K + U_{int}(\mathbf{r}), \quad (6)$$

where K is the kinetic energy and $U_{int}(\mathbf{r})$ is the system of interest's interaction potential, where \mathbf{r} is a function of the set of particle coordinates, and with have a second system in the same thermodynamic phase of the system of interested, that we known its Helmholtz free-energy (analytical or numerical) and is it described by the Hamiltonian H_{ref} , given by

$$H_{ref} = K + U_{ref}(\mathbf{r}_i), \quad (7)$$

with $U_{ref}(\mathbf{r})$ its interaction potential.

A typical functional form of $H(\lambda)$ that coupling the system of interest and reference is given by a linear interpolation as follow

$$H_\lambda = \lambda H_{int} + (1 - \lambda) H_{ref}, \quad (8)$$

note that this form allow a continuous switching between H_{int} and H_{ref} by varying the coupling parameter λ between $\lambda_i = 1$ and $\lambda_f = 0$. According to the Eq. 1, the reversible work is given by

$$W_{rev} = \int_{\lambda_i}^{\lambda_f} \langle U_{int} - U_{ref} \rangle d\lambda \quad (9)$$

and its corresponding the dynamical work estimator for the forward process is given by

$$W_{dyn}^{i \rightarrow f} = \int_0^{t_s} \frac{d\lambda}{dt} (U_{int} - U_{ref}) dt, \quad (10)$$

combining the average results obtained from a number of independent realizations in the forward and backward switching processes, the desired Helmholtz free-energy is estimated as

$$F_{int} = F_{ref} + \frac{1}{2} [\overline{W}_{dyn}^{i \rightarrow f} - \overline{W}_{dyn}^{f \rightarrow i}], \quad (11)$$

since know the Helmholtz free-energy of reference F_{ref} , for the solids systems, either crystalline or amorphous, the choice of reference system is straightforward, with the Einstein crystal[11, 2, 12] providing a system with analytically

known Helmholtz free energy. For fluid-phase systems recently was proposed that the UF model[3, 4], which provide robust reference systems that allow accurate fluid-phase Helmholtz free-energy.

2.2. Gibbs free-energy as a function of the temperature: Reversible Scaling method

Suppose the Gibbs free-energy $G_{int}(P, T_0)$ of a system of interest is known at some temperature T_0 and fixed pressure P , and we now wish to determine $G_{int}(P, T)$ for other temperatures T along isobaric path. An efficient alternatively can be achieved using a single simulation the reversible-scaling (RS) technique[12]. The RS method in the NPT ensemble[8] is based on the following parametric Hamiltonian

$$H_{RS}(\lambda) = K + \lambda U_{int}(\mathbf{r}) + P_S(\lambda)V, \quad (12)$$

in this case this Hamiltonian represent the enthalpy of the scaled system, where the potential energy is scaled by the coupling parameter and P_S the external pressure on the scaled system. The configurational and volume part of the classical partition function in the NPT ensemble $Z_{RS}(P_S(\lambda), \lambda)$ of the RS Hamiltonian at temperature T_0 and pressure P_s is given by

$$Z_{RS}(P_S(\lambda), \lambda) = \int dV \exp[-P_S(\lambda)V/k_B T_0] \int_V d^{3N} \mathbf{r} \exp[-\lambda U_{int}(\mathbf{r})/k_B T_0] = Z_{int}(P, T), \quad (13)$$

which is equal to that of the partition function of the system of interest at temperature T and pressure P using the following scaling relations:

$$T = \frac{T_0}{\lambda} \quad (14)$$

and

$$P_S(\lambda) = \lambda P, \quad (15)$$

with these conditions (Eqs. 13, 14 and 15) the Gibbs free energies of the scaled G_{RS} and physical systems G_{int} , are related according to

$$G_{int}(P, T) = \frac{G_{RS}(P_S(\lambda), T_0; \lambda)}{\lambda} + \frac{3}{2} N k_B T_0 \frac{\ln \lambda}{\lambda} \quad (16)$$

where N is the number of atoms, Eq. 16, implies that each value of in the scaled Hamiltonian H_{RS} at a fixed temperature T_0 and scaled pressure $P_S(\lambda)$

corresponds to the system of interest described by H_{int} at a temperature T and pressure P . Thus, the problem of calculating the free-energy of the physical system as a function of temperature T at fixed pressure P can be obtained from $H_{RS}(\lambda)$ by varying the scaling parameter λ and scaling pressure $P_S(\lambda)$ at fixed temperature T_0 , in this case we can identify the driving force as

$$\frac{\partial H_{RS}(\lambda)}{\partial \lambda} = U_{int}(\mathbf{r}) + \frac{dP_S(\lambda)}{d\lambda}V, \quad (17)$$

the reversible work in the RS method is given by

$$W_{rev}(\lambda) = \int_1^\lambda \left(\langle U_{int} \rangle + \frac{dP_S(\lambda')}{d\lambda'} \langle V \rangle \right) d\lambda', \quad (18)$$

the reversible work in Eq. 18 can be obtained within very good accuracy through the AS method, can be applied to estimate the forward dynamical work, with $\lambda(t)$ varying from $\lambda(0) = 1$ to $\lambda(t_s) = \lambda_f$

$$W_{dyn}^{i \rightarrow f} = \int_0^{t_s} \frac{d\lambda}{dt} \left(U_{int} + \frac{dP_S(\lambda)}{d\lambda} \Big|_{\lambda(t)} \right) dt \quad (19)$$

Also carrying out the scaling process in the opposite direction and using Eq. 4, the $G_{int}(P, T)$ on the temperature interval between T_0 and T_0/λ_f at fixed pressure P is given by

$$G_{int}(P, T) = \frac{G_{int}(P, T_0)}{\lambda} + \frac{f}{2} N k_B T_0 \frac{\ln \lambda}{\lambda} + \frac{1}{2\lambda} [\overline{W}_{dyn}^{1 \rightarrow \lambda} - \overline{W}_{dyn}^{\lambda \rightarrow 1}], \quad (20)$$

where λ varies between 1 and λ_f .

It is important to note that the application of this approach requires knowledge of the absolute Gibbs free-energy of the system of interest at a temperature T_0 and pressure P , which can be computed knowing Helmholtz free-energy at temperature T_0 and the average volume V of the system that correspond to the external pressure P , using the following thermodynamics relation

$$G_{int}(P, T_0) = F_{int}(V, T_0) + PV \quad (21)$$

where the $F(T_0, V)$ can be determine by applied the AS method, detailed 2.1.

2.3. Gibbs free-energy as a function of pressure: Adiabatic Switching method

Suppose the Gibbs free-energy $G_{int}(P_0, T)$ of a system of interest is known at some pressure P_0 and fixed temperature T , and we now wish to determine $G_{int}(P, T)$ for other pressure P along isothermal path, where the Hamiltonian of the interest system is

$$H_{int} = K + U_{int}(\mathbf{r}) + PV, \quad (22)$$

if we take the external pressure as coupling parameter, the work associated with a reversible process along a path connecting the physical system at the reference pressure P_0 to the system at a pressure of interest P is

$$G_{int}(P, T) - G_{int}(P_0, T) = \int_{P_0}^P \left\langle \frac{\partial H}{\partial P'} \right\rangle dP' = \int_{P_0}^P \langle V \rangle dP' \equiv W_{rev}, \quad (23)$$

where the brackets in Eq. 23 indicate the equilibrium average of the volume in the isothermal-isobaric ensemble. An efficient alternative can be achieved by using the AS method[5], the integral can be evaluate along a single non-equilibrium simulation during which the value of external pressure $P(t)$ changes dynamically, in such a way that, at the beginning of the simulation $P(0) = P_0$ and at the end $P(t_s) = P$. In this case the reversible work will be estimated in terms of the dynamical work

$$W_{dyn} = \int_0^{t_s} \left. \frac{dP(t)}{dt} \right|_t V(t) dt. \quad (24)$$

In this switching process not only the initial and final points on the trajectory correspond to physical systems, as it is usual in AS simulations, but the information gathered at the intermediate states of the path also has physical meaning. As a consequence, one obtains the Gibbs free-energy of a system in a wide interval of pressure, provided that the Gibbs free-energy of the system of interest in a reference state is known.

$$G_{int}(P, T) = G_{int}(P_0, T) + \frac{1}{2} [\overline{W}_{dyn}^{i \rightarrow f} - \overline{W}_{dyn}^{f \rightarrow i}]. \quad (25)$$

3. Dynamic Clausius-Clapeyron integration

First-order phase transitions for pure substances, are usually represented as lines in a PT diagram, who indicated the phase boundaries between the

phases and its slope can be describe by the Clausius–Clapeyron equation (CCE), which uses thermodynamic properties of both phase at the coexistence. The CCE in the PT diagram can be written in several forms, the most common of which is

$$\frac{dP}{dT} = \frac{\Delta H}{T\Delta V} \quad (26)$$

where ΔH and ΔV are the molar enthalpy and volume differences between the two phases, respectively. The CCE is remarkable because if a point of the coexistence curve is known, one can obtain the whole phase boundary from Eq. 26.

In the nineties Kofke[13] proposed a method that employs the CCE combined with results from computer simulations to calculate phase boundaries. The method is very effective, however, it requires a series of independent equilibrium simulations of both phases of interest, which quite demanding in terms of computing time.

In order to avoid performing a series of independent equilibrium simulations for each phase necessary to map the phase boundaries, de Koning et al.[8] based on a similar idea to the RS method, proposed a method in which the integration of Clausius–Clapeyron equation is performed dynamically. Starting at a single point of the coexistence curve, this technique allows the exploration of the coexistence curve over a wide range of states from a single non-equilibrium simulation for both phases simultaneously.

Thus, starting from a known condition of phase coexistence, considering both phases I and II , what happens when the Gibbs free energies of both phases are equalized $G_{s,I} = G_{s,II}$, if applied reversible perturbations $d\lambda$ and $d\lambda(dP_S/d\lambda)$, the Gibbs free energies of the scaled systems will change according to

$$dG_{S,I} = dW_{rev,I} = d\lambda \left[\langle U_{int} \rangle_I + \frac{dP_S}{d\lambda} \langle V \rangle_I \right] \quad (27)$$

and

$$dG_{S,II} = dW_{rev,II} = d\lambda \left[\langle U_{int} \rangle_{II} + \frac{dP_S}{d\lambda} \langle V \rangle_{II} \right], \quad (28)$$

where all ensemble averages are evaluated at the temperature T_0 , scaling parameter λ , and scaled pressure $P_S(\lambda)$. In order to keep the phase-coexistence upon the application of this disturbance, we must have that $dG_{S,a} = dG_{S,b}$,

from which we get the following relationship between pressure and temperature of the scaled systems,

$$\frac{dP_S}{d\lambda} = - \left(\frac{\langle U_{int} \rangle_I - \langle U_{int} \rangle_{II}}{\langle V \rangle_I - \langle V \rangle_{II}} \right), \quad (29)$$

this equation is the CCE the scaled systems, where the temperature is represented by the coupling parameter λ .

Similarly to what is done to estimate the free energy from non-equilibrium simulations, we can change Eq. 29 in a way that the parameter λ is varied dynamically, transforming it into the dynamic Clausius-Clapeyron equation

$$\frac{dP_S}{dt} = - \frac{d\lambda}{dt} \left(\frac{U_{int,I}(t) - U_{int,II}(t)}{V_I(t) - V_{II}(t)} \right), \quad (30)$$

where ensemble averages of the potential energies and volumes have been replaced by instantaneous values along the time-dependent process. Provided the dynamic process is ideally reversible, the coexistence curve is given by

$$P_{S,coex}(\lambda(t_s)) = P_{S,coex}(\lambda = 1) - \int_0^{t_s} \frac{d\lambda}{dt} \left(\frac{U_{int,I}(t) - U_{int,II}(t)}{V_I(t) - V_{II}(t)} \right) dt. \quad (31)$$

Given an initial coexistence condition, the integration of this equation then provides a dynamical estimator for the entire coexistence curve from a single non-equilibrium simulation in which both phases are considered simultaneously. In practice, one ought to consider finite changes of the parameter λ in Eq. 31, in such a way we obtain

$$P_{S,coex}(\lambda_{k+1}) = P_{S,coex}(\lambda_k) - (\lambda_{k+1} - \lambda_k) \left(\frac{\Delta U_{I-II,k}}{\Delta V_{I-II,k}} \right) \quad (32)$$

where $\Delta U_{I-II,k} = U_{int,I}(\mathbf{r}_k) - U_{int,II}(\mathbf{r}_k)$ and $\Delta V_{I-II,k} = V_{I,k} - V_{II,k}$, the initial value of λ is always set to be equal to 1, and it is varied according to Eq. 14 in order to attain the desired temperature T , depending on the rate of change of λ a given scaled coexistence pressure $P_{S,coex}(\lambda)$ may be attained for different values of λ from the Eq. 32 and using the scaling relation Eq. 15, we obtain the coexistence pressure P_{coex} , this means that we obtain the coexistence curve as the pressure coexistence in wide interval of the temperature $P_{coex}(T)$.

If the coexistence line has a small slope (in absolute value) i.e. the pressure derivative with respect the temperature has a small value, which is

common in solid-solid coexistence lines, it is more convenient use the λ parameter as control parameter and the Eq. 32. If, on the other hand, the coexistence line is expected to have a large slope (in absolute value) i.e. the pressure derivative with respect the temperature has a large value, which is common in solid-fluid and fluid-fluid phase boundaries, in these case is more convenient use the pressure P as control parameter, which can be obtained by inverting the relationship between λ and $P_{S,coex}$ in the Eq. 32

$$\lambda_{k+1} = \lambda_k \left(\frac{1 + P_k \Delta V_{I-II,k} / \Delta U_{I-II,k}}{1 + P_{k+1} \Delta V_{I-II,k} / \Delta U_{I-II,k}} \right) \quad (33)$$

and use the scaling relations Eqs. 15 and 14, we obtain the coexistence line as the temperature coexistence in wide interval of pressure $T_{coex}(P)$.

Evidently, the dynamic estimators of $P_{coex}(T_k)$ or $T_{coex}(P_k)$ are subject to errors associated with the irreversible nature of the time-dependent scaling process, however those effects decreases quickly with increasing the number of simulation step, allowing accurate determination of an entire phase boundary from a single, relatively short dynamic scaling simulation.

4. Application: results and discussion

In this section we describe the implementation of the dCCI method describe previously and the widely used Molecular Dynamics code LAMMPS. We demonstrate the application of the NE methods used to calculated coexistence conditions by computed the Gibbs free-energy of the phases in wide interval the temperature and pressure, and with the use of the dCCI method us compute the phase boundaries, in this case for the Silicon described by the Stillinger-Weber (SW)[9] potential. Complete LAMMPS scripts, source code and auxiliary files are available under request.

Initially we need determine the coexistence points: (i) the melting temperature of the silicon diamond phase (Si-cd) at 0.0 GPa. Next, we compute (ii) the melting temperature of the silicon β -tin phase (Si- β -tin) at 15.0 GPa and (iii) the coexistence pressure between the Si-cd and Si- β -tin at 400 K. Finally with these coexistence points (iv) we apply the dCCI method to calculate the phase diagram of silicon and determine the triple point predict by the SW potential.

4.1. Melting points of silicon:

First, we will determine the melting points of the Si-cd and Si- β -tin phases at zero pressure and 15.0 GPa, respectively, for this issue we need compute

the Gibbs free-energy curves $G(P, T)$ for the solids and liquid phases and find the temperature T_m at which they cross. To achieve this we follow the Ref.[2, 4], which provides details of methodologies for calculating the free energy of the solid and liquid phases using the LAMMPS package.

We use computational cells containing 8000 atoms for the Si-cd and liquid phases, and for the Si- β -tin was use 7448 atoms, all systems subject to periodic boundary conditions. Pressure and temperature control was obtained using a Parrinello-Rahman[14] barostat and a Langevin[15] thermostat. The corresponding equations of motion were integrated using velocity-Verlet algorithm with a time step of $\Delta t = 1$ fs.

To compute the Gibbs free-energy as a function of the temperature of Si-cd at zero-pressure, first we determine the equilibrium volume at $T_1 = 400$ K, by initial equilibration of 0.2 ns and then is determine the average value of the volume over a time interval of 1.0 ns. Next, we compute the Gibbs free-energy at a reference temperature at 400 K, using as reference system the Einstein crystal with a spring constant of $6.113 \text{ eV}/\text{\AA}^2$, the systems was equilibrated during 0.1 ns prior to the switching runs, and the unbiased dynamical-work estimators were obtained from 10 independent forward and backward realizations using switching times between 0.01 ns to 0.2 ns. Finally, we use the RS method to compute the Gibbs free-energy curve as a function of temperature at 0.0 GPa for Si-cd. The RS path chosen was such the scaling parameter λ is varied between $\lambda = 1$ to $\lambda = \lambda_f = 400/2000$, such that the covered temperature range is that between $T_0 = 400$ K and $T_f = 2000$ K, with a switching time of $t_s = 0.5$ ns and determine the dynamical work as the average over ten independent realizations of the RS process in forward and backward directions. Full details of the methodology to compute the Gibbs free-energy curve as a function of temperature at zero pressure are described in Ref.[2].

Now we compute at zero-pressure the absolute Gibbs free-energy as a function of the temperature of liquid phase. We start by determining the equilibrium volume at $T_2 = 2200$ K, by initial equilibration of 0.2 ns and then is determine the average value of the volume over a time interval of 1.0 ns. Next, we compute the Gibbs free-energy at a reference temperature at 2200 K, using as reference system the UF model[3], with the following parameters: $p=25$ and $\sigma = 2.0$, the systems was equilibrated during 0.1 ns prior to the switching runs, and the unbiased dynamical-work estimators were obtained from 10 independent forward and backward realizations using switching times between 0.01 ns to 0.1 ns. Finally, we use the RS method

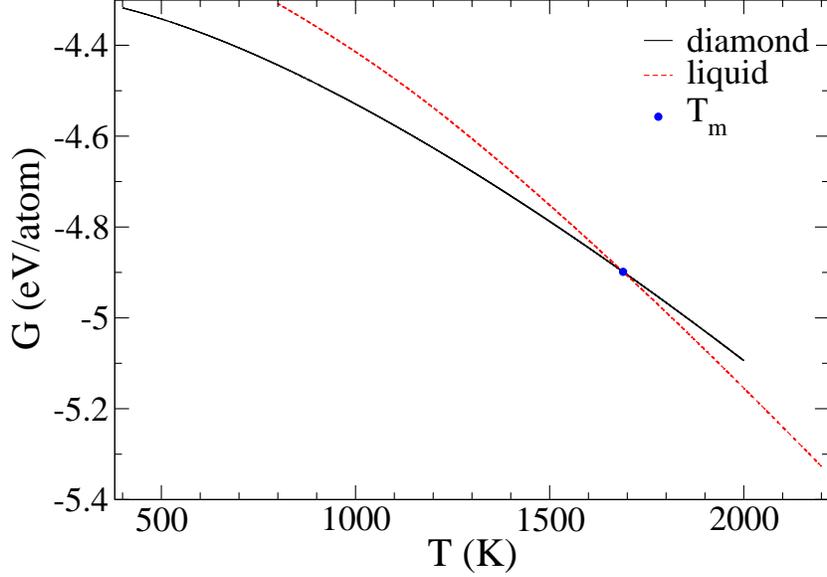


Figure 1: Gibbs free energy per atom of the Si-cd and liquid phases at zero pressure. The crossing of the curves indicates the fusion temperature at zero pressure.

to compute the Gibbs free-energy curve as a function of temperature at 0.0 GPa for liquid phase. The RS path chosen was such the scaling parameter λ is varied between $\lambda = 1$ to $\lambda = \lambda_f = 2200/800$, such that the covered temperature range is that between $T_0 = 2200$ K and $T_f = 800$ K, with a switching time of $t_s = 0.5$ ns and determine the dynamical work values $W^{1 \rightarrow \lambda}$ and $W^{\lambda \rightarrow 1}$ as the average over ten independent realizations of the RS process in forward and backward directions. Full details of the calculation of Gibbs free-energy curve as a function of temperature at zero pressure used for the liquid phase are described in Ref.[4]. In the figure 1 is show the melting temperature of Si-cd at 0.0 GPa the value is $T_m = 1689.2(3)$ K this values is agreement with previous reported in Ref.[16].

After computed the melting point at zero pressure, we now determine the second melting of silicon at 15.0 GPa by the crossing of the absolute Gibbs free energies between the Si- β -tin and the liquid. This is accomplished using a similar procedure using for the Si-cd. To compute the absolute Gibbs free-energy as a function of the temperature for the Si- β -tin phase, we determine the equilibrium volume at $T_1 = 400$ K, by initial equilibration of 0.2 ns and then is determine the average value of the volume over a time interval of 1.0 ns. Next, we compute the Helmholtz free-energy at the temperature

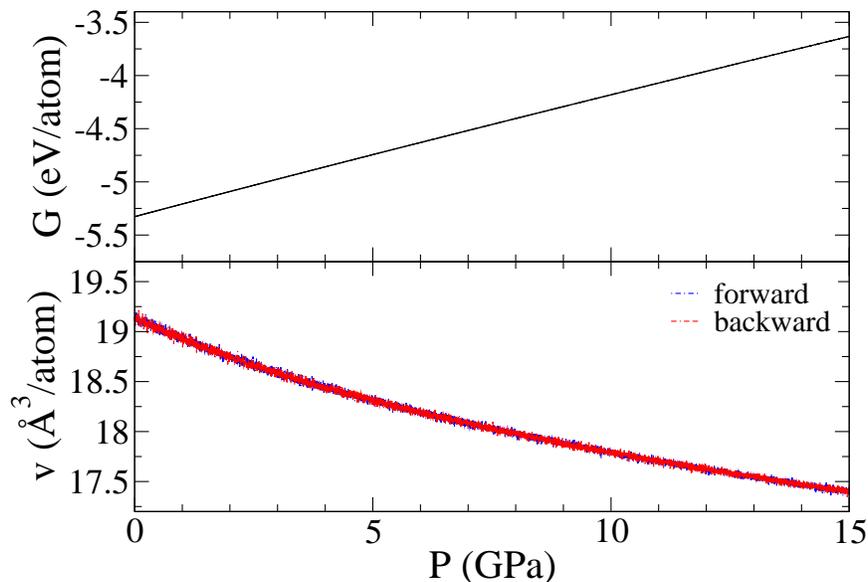


Figure 2: **(Up)** Gibbs free-energy of liquid as function of pressure. **Down** volume per atom as function of the dynamical pressure in the forward and backward process

of 400 K (Eq. 11), using as reference system the Einstein crystal with a spring constant of $1.362 \text{ eV}\text{\AA}^2$, the systems was equilibrated during 0.1 ns prior to the switching runs, and the unbiased dynamical-work estimators were obtained from 10 independent forward and backward realizations using switching times between 0.01 ns to 0.5 ns, the Gibbs free-energy is obtained by from the Eq. 21. Finally, we use the RS method to compute the Gibbs free-energy curve as a function of temperature at 15.0 GPa, in this case during the RS path additional to the scaling of the force by the `fix adapt` command in LAMMPS, we need scaling the external pressure of the barostat too, in order to take account the effect of volume change of the system, for this issue we modified the `fix npt` (`fix nph`) include a new tag the `ners`, which multiply the external pressure by the scaling parameter λ . This is achieved using the following `fix` commands in the LAMMPS script:

```
variable lambda equal 1/(1+(elapsed/>{t_s})*(1/>{lf}-1))
fix f1 all nph aniso 15000.0 15000.0 1.0 ners v_lambda
```

The RS path chosen was such the scaling parameter λ is varied between $\lambda = 1$ to $\lambda = \lambda_f = 400/1600$, such that the covered temperature range is that between $T_0 = 400$ K and $T_f = 1600$ K. The temperature dependence of the Gibbs free-energy is then computed using Eq. 20, with a switching time

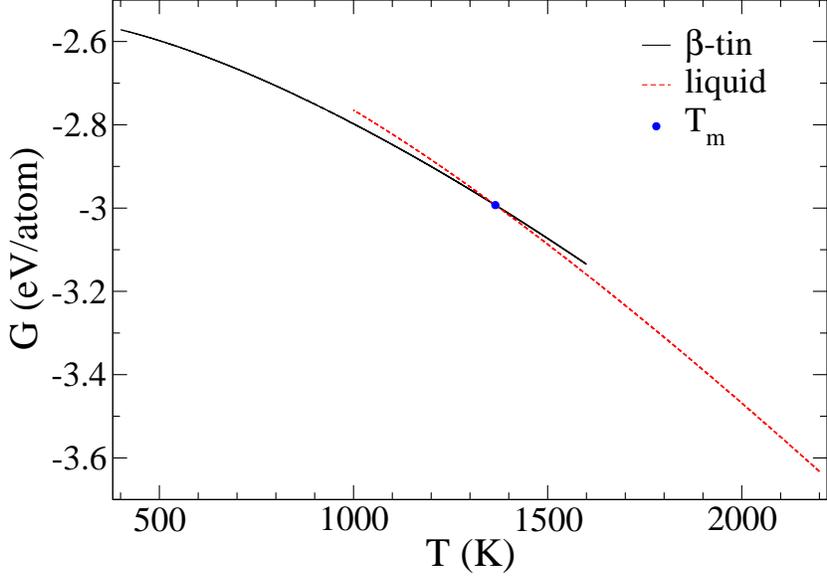


Figure 3: Gibbs free energy per atom of the Si- β -tin and liquid phases at 15.0 GPa. The crossing of the curves indicates the fusion temperature at 15.0 GPa.

of $t_s = 0.5$ ns, to determine the dynamical work values $W^{1 \rightarrow \lambda}$ and $W^{\lambda \rightarrow 1}$ as the average over ten independent realizations of the RS process in forward and backward directions.

To compute the absolute Gibbs free-energy as a function of the temperature of liquid phase at 15.0 GPa, we follow a different procedure, first we determine the Gibbs free-energy as function of the pressure at 2200 K by using the AS method (Eq. 25) change the external pressure P dynamically between 0.0 GPa to 15.0 GPa. The system was equilibrated during 0.1 ns prior to the switching runs, and the unbiased dynamical work (Eq. 24) were obtained from 10 independent forward and backward realizations using switching times between 0.01 ns to 0.2 ns. We observed a very quickly convergence of dynamical work to switching times 0.05 ns. Finally, we use the RS method to compute the Gibbs free-energy curve as a function of temperature at 15.0 GPa for the liquid phase with a identical procedure to the Si- β -tin. This is achieved using the following fix commands in the LAMMPS script:

```
variable lambda equal 1/(1+(elapsed/>{t_s})*(1/{lf}-1))
fix f1 all nph iso 15000.0 15000.0 1.0 ners v_lambda
```

The RS path chosen was such the scaling parameter λ is varied between

$\lambda = 1$ to $\lambda = \lambda_f = 2200/1000$, such that the covered temperature range is that between $T_0 = 2200$ K and $T_f = 1000$ K. The temperature dependence of the Gibbs free-energy is then computed using Eq. 20, with a switching time of $t_s = 0.5$ ns, to determine the dynamical work values $W^{1 \rightarrow \lambda}$ and $W^{\lambda \rightarrow 1}$ as the average over ten independent realizations of the RS process in forward and backward directions. The figure 3 show the melting temperature of silicon at 15.0 GPa is $T_m = 1365.3(3)$ K.

4.2. Pressure coexistence point between solids phases

To determine the pressure coexistence of solids phases at 400 K, we compute the Gibbs free-energy curves $G(P, T)$ for both solids as function of pressure along isothermal path by apply the AS method (Eq. 25) with the knowledge of the Gibbs free-energy at 400 K for both solid phases, we compute the dynamical work for the Si-cd change the pressure dynamically between 0.0 GPa to 15.0 GPa, the systems was equilibrated during 0.1 ns prior to the switching runs, and the unbiased dynamical mechanical work estimators were obtained from 10 independent forward and backward realizations using : ly
conver in

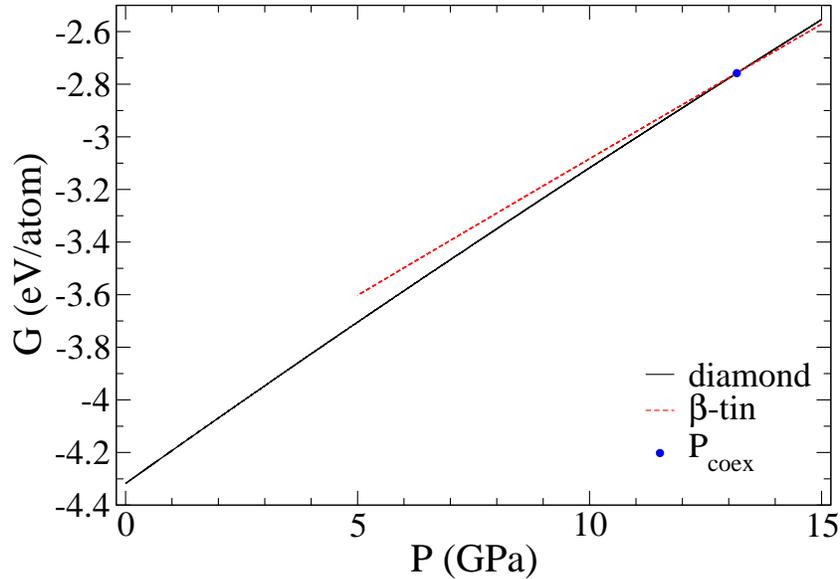


Figure 4: Gibbs free energy per atom of the Si-cd and Si- β -tin phases at 400 K. The crossing indicate a pressure coexistence at 400 K.

the pressure is change dynamically between 15.0 GPa to 5.0 GPa, with the same protocol for the Si-cd, again is observed a very quickly convergence of dynamical work to switching times 0.05 ns. The Fig. 4 show the coexistence pressure at 400K of the solid phases with the value of $P_{coex} = 13.17346(5)$ GPa, in agreement with previous reported by Romano et. al[17].

4.3. Phase diagram of silicon:

First, we determine the phase boundary between the Si-cd and liquid phase, by using the coexistence point determined at 0.0 GPa, as an initial condition to applied the dCCI method, in this case, the external pressure was chosen as the independent variable in the integration process and varied linearly between the boundaries $P = 0.0$ GPa and $P = 10.2$ GPa for scaling times between 1 ps to 200 ps. Each process was started from equilibrated configurations in both cells corresponding to the known coexistence condition at $P = 0.0$ GPa.

This is achieved using the following commands `fix adapt/dcci` and `dcci` together, the `fix adapt/dcci` has a similar functionality of the `fix adapt` but in this case the scaling parameter is controlled by the `dcci` command, must run with one or more processors per each phase. The use of these commands in the LAMMPS script are:

```
fix f1 all nph iso ${Pcoex} ${Pcoex} ${Pdamp}
fix f2 all langevin ${Tcoex} ${Tcoex} ${Tdamp} 1234 zero yes
fix f3 all adapt/dcci ${lambda} pair sw fscale * *
dcci ${Tcoex} ${Pcoex} ${lambda} f3 f1 ${t_s} press ${Pi} ${Pf}
```

The `dcci` command perform the time-dependent calculation of coexistence curve, $\text{\${Tcoex}}$ and $\text{\${Pcoex}}$ are the initial coexistence point, $\text{\${lambda}}$ is the scaling parameter and must definite too in the `fix adapt/dcci`, who is identify whit the fix id `f3`, and also the `dcci` need to control the external pressure of the barostat who is identify with the fix id `f1`, $\text{\${t_s}}$ is the scaling time, finally the syntax `press ${Pi} ${Pf}`, indicated the initial and final pressure along the coexistence the curve to obtain the coexistence temperature as a function of the pressure i.e. $T_{coex}(P)$.

In the figure 5 is show the phase boundaries between Si-cd and liquid, we observe a convergence for scaling times above 50.0 ps. In order to estimate the effects associated with the irreversible nature of dCCI, we investigated the convergence of the coexistence temperatures as a function of the scaling time t_s , compared with the melting point of Si-cd at $P = 9.4$ GPa calculated by the AS and RS methods (see supp. materials).

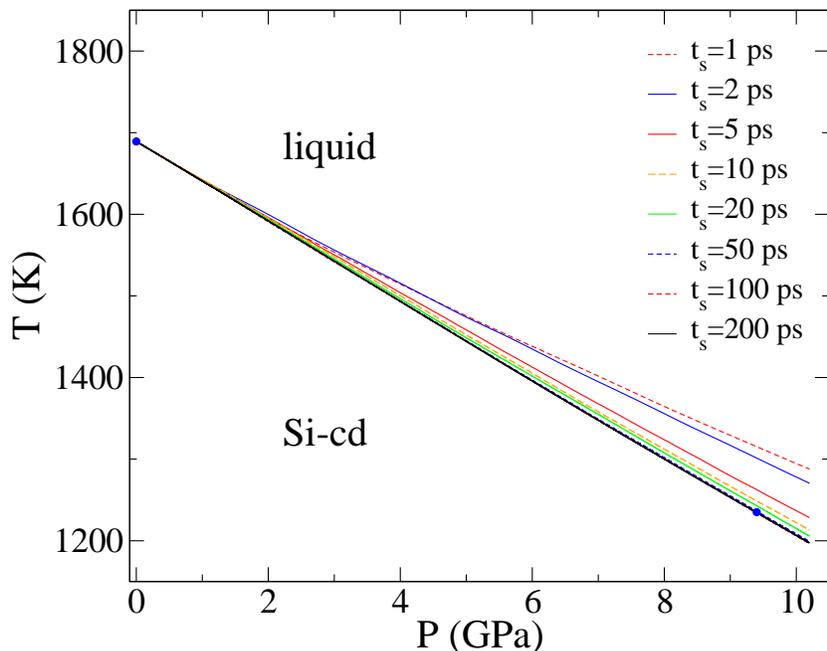


Figure 5: Melting curve between Si-cd and liquid for different scaling times. The points represent the melting temperature at zero pressure and 9.4 GPa, by using the NE methods

The figure 6 shows the value of the coexistence temperature at the pressure $P=9.4$ GPa determined from dCCI runs. The coexistence temperature converges near 50 ps per process, reaching a plateau above 100 ps.

Now we determine the other phase boundaries between the Si- β -tin and liquid phase, by using the coexistence point determined at 15.0 GPa, as an initial condition to applied the dCCI method, the pressure varied linearly between the boundaries $P=15.0$ GPa and $P=9.4$ GPa for an scaling time of 100 ps, the procedure is practically identically but with a minor difference, in the previous case for Si-cd and liquid phases we use isotropic volume fluctuation, because both phase present isotropic symmetry `fix f1 all npH iso`, in this case, the Si- β -tin phase present anisotropic symmetry, to perform correct volume fluctuations for each system, i.e. isotropic for liquid `fix npH iso` and anisotropic `fix npH aniso` for the Si- β -tin, we need define a different style of barostat for each phase in the LAMMPS script, this is achieved using the following commands:

```
variable barostat word iso aniso
fix f1 all npH ${barostat} ${Pcoex} ${Pcoex} ${Pdamp}
```

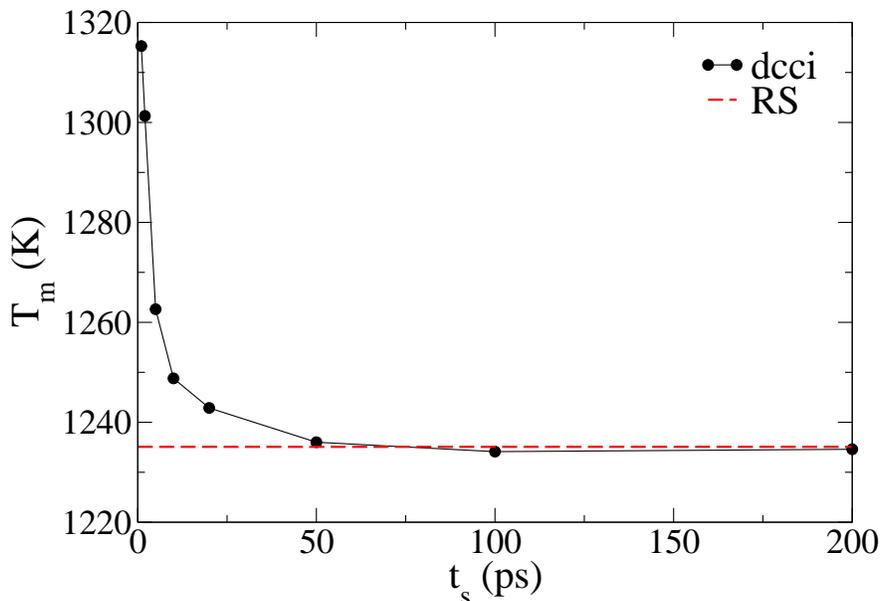


Figure 6: The points indicated the melting point of Si-cd at $P=9.4$ GPa as function of scaling time for the dCCI method and the dashed red line correspond to the value by the RS method.

```
fix f2 all langevin ${Tcoex} ${Tcoex} ${Tdamp} 1234 zero yes
fix f3 all adapt/dcci ${lambda} pair sw fscale * *
dcci ${Tcoex} ${Pcoex} ${lambda} f3 f1 ${t_s} press ${Pi} ${Pf}
```

In the next, we determine the coexistence line between the solids phase, by using the coexistence point determined at 400 K, as an initial condition to applied the dCCI method, in this case is more suitable the control of the temperature, because in the coexistence curve of the solid-solid phase transition is present a small change of the pressure in a large interval of temperature, therefore the temperature is varied linearly between 400 K to 1250 K for a scaling time of 100 ps, each process was started from equilibrated configurations in both cells corresponding to the known coexistence condition at 400 K and with isotropic and anisotropic volume fluctuation for the Si-cd and Si- β -tin, respectively, this is achieved using the following commands:

```
variable barostat word iso aniso
fix f1 all nph ${barostat} ${Pcoex} ${Pcoex} ${Pdamp}
fix f2 all langevin ${Tcoex} ${Tcoex} ${Tdamp} 1234 zero yes
fix f3 all adapt/dcci ${lambda} pair sw fscale * *
```

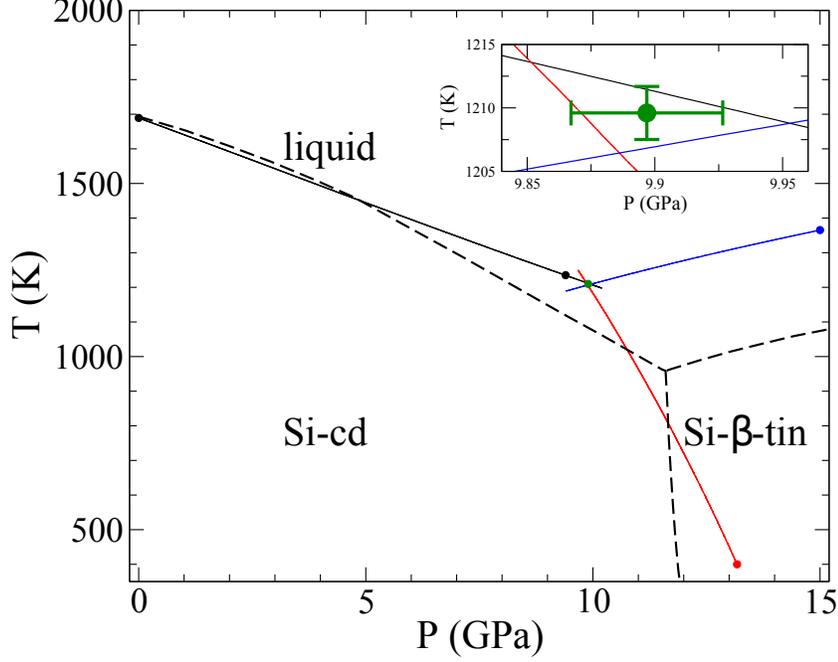


Figure 7: Phase boundaries between the silicon phases by dCCI method. The dashed black lines correspond to phenomenological results[18]. **Inset:** triple point is indicated by the crossing of coexistence curves.

`dccci $Tcoex $Pcoex $lambda f3 f1 $t_s temp $Ti $Tf`
 the syntax is similar to describe previously, but in this case we need to indicate the control of the temperature in the `dccci` command, by the following command `temp $Ti $Tf`, that indicated the initial and final temperature along the coexistence the curve to obtain the coexistence pressure as a function of the temperature ($P_{coex}(T)$).

Finally, in the figure 7 is show the phase diagram of silicon model by the SW potential between the three phases considered in this paper. The found triple point is $T_p=(1210(2) \text{ K}, 9.90(3) \text{ GPa})$, in agreement in agreement with previous reported by Romano et. al[17] and also we compared our results with those predicted by Yang et al.[18] using the Thermo-Calc[19] software, we note that there are differences between the phase diagram using the non-equilibrium methods and the Thermo-Calc, where the origin of these differences is attributed to the potential model chosen to represent the silicon

phases, since originally the Stillinger-Weber potential was developed to study silicon in the diamond and liquid phase at low pressures, as can be observed in the agreement of the coexistence curves of our results and those predicted by Yang for pressures less than 5 GPa. Despite the qualitative difference between the phases diagram predict by the non-equilibrium methods and the phenomenological results, is observed quantitative agreement between the phases diagrams, as negative slope of the fusion curve of the silicon diamond phase, positive slope of the fusion curve of the silicon β -tin phase and negative slope of the phase boundaries between the solids phases.

5. Summary

In this paper provides a guide for computing the Gibbs free-energy along isothermal and isobaric path and also the phase boundaries, by using non-equilibrium free-energy methods and dCCI method within the LAMMPS MD simulation package. In addition to describing LAMMPS implementation details and making available the computational tools in the form of full source code, scripts and auxiliary files.

As illustrative example, is determine phase diagram of silicon model by SW potential. Initially, is determine the coexistence points between the phases of silicon by the use of AS and RS methods, that allow us to Gibbs free-energy of the phases in wide interval of temperatures and pressures in efficient way. After that with the coexistence points between the phases we apply the dCCI method to determine the phase boundaries of Silicon by single non-equilibrium simulation.

The techniques described in this paper, together with the supplied source code, scripts and post-processing files, provide a platform on compute the phase boundaries for atomistic systems can be easily and efficiently computed using the LAMMPS code.

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